

Republic of Iraq Ministry of Higher Education and Scientific Research University of Diyala College of Science Department of Physics



Enhancement of Gas Sensing Properties of Metal Oxides Thin Films by Embedding of Noble Metals Nanoparticles

A thesis

Submitted to the Council of the College of Science University of Diyala in Partial Fulfillment of Requirements for the Degree of Doctor of Philosophy in Physics

By

ASAAD AHMED KAMIL

Supervised By

Prof. Dr. Nabeel Ali Bakr Prof. Dr. Tahseen Hussien Mubarak

2022 A.D

1444 A.H

بسم الله الرحيم الرحيم

Dedication

То

The lights of my life soul Father & Mother

The lights of my eyes my wife, my son Mustafa, my daughters, Tabark and Yusur

To My Lovely Family My Brother and My Sisters.

To All My Friends.

All faithful hearts who helped me in the journey of my life.

Asaad

Acknowledgement

First and foremost, I would like to thank Almighty Allah for giving me the strength, knowledge, ability and opportunity to undertake, persevere and complete this research. Without his blessings, this achievement would not have been possible. I also thank our prophet Muhammad (peace and blessings of Allah be upon him) who invites us to science and work. I would like to express my sincere appreciation and deep gratitude to my supervisors, Prof. Dr. Nabeel Ali Bakr and Prof. Dr. Tahseen Hussien Mubarak for suggesting the topic of this thesis, intuitive insight, constant encouragement, unconditional support and unlimited cooperation extended to me during the course of my research work.

I would like to express my profound gratitude to Prof. Dr. Sabah A. Salman, Prof. Dr. Ziad T. Khodair, Assist. Prof. Dr. Jasim M. Mansoor, Assist. Prof. Dr. Mohammed Hameed, Assist. Prof. Dr. Jassim M. Khalel, Prof. Dr. Issam M. Ibrahim (Baghdad University, College of Science), Assist. Prof. Dr. Issam H. Hameed, Prof. Firas M. Hadi and Assist. Prof. Faisal G. Hammody for their kind cooperation and constant support. I am highly indebted to encouragement throughout my study.

Special thanks are extended to the University of Diyala, College of Science, Department of Physics, the head of the department Assist. Prof. Dr. Amar A. Habeeb, and all the Staff of the College of Science and Department of Physics for their assistance.

I would like to express my profound gratitude to the members of the College of Science council and all colleagues of College of Science.

I am grateful to my colleagues in laboratory at Physics Dept. College of Science, University of Diyala, (Karrar, Ali Menhal, Saif, Laith, Hala, Israa Mohammed and Haidar). I would also like to thank Dr. Fuaad (Baghdad University, College of Science), Dr. Adnan Abo Ayman, Dr. Mustafa Zaid, Marwa Jwameer for their help in making measurements.

Published and Accepted Research Articles

1. A. A. Kamil, N. A. Bakr, T. H. Mubarak and J. Al-Zanganawee "Synthesis and study of the optical and structural properties of Au and Ag nanoparticles by pulsed laser ablation (PLAL) technique "Digest Journal of Nanomaterials and Biostructures Vol. 16, No. 4, October-December 2021, p. 1219-1226.

2. Asaad A. Kamil, Nabeel A. Bakr, Tahseen H. Mubarak and J. Al-Zanganawee "Effect of Au and Ag Nanoparticles Addition on the morphological structural and Optical Properties of ZnO Thin Films Deposited by Sol- Gel Method" Journal of Ovonic Research Vol. 18, No. 3, May - June 2022, p. 431 - 442

We certify that this thesis entitled "Enhancement of Gas Sensing Properties of Metal Oxides Thin Films by Embedding of Noble Metals Nanoparticles" submitted by (ASAAD AHMED KAMIL) was prepared under our supervision at the Department of Physics, College of Science, University of Diyala in a partial fulfillment of the requirements needed to award the Degree of Doctor of Philosophy (Ph. D.) in Science of Physics.

| Signature: | Signature: |
|-------------------------------------|-------------------------------------|
| Name: Dr. Nabeel A. Bakr | Name: Dr. Tahseen H. Mubarak |
| Title: Professor | Title: Professor |
| Address: Dep.of Physics, College of | Address: Dep.of Physics, College of |
| Science, University of Diyala | Science, University of Diyala |
| Date: / / 2022 | Date: / / 2022 |

Head of the Physics Department

In view of the available recommendations, I forward this thesis for debate by the examination committee.

Signature:

Name: Dr. Ammar A. Habeeb

Title: Assistant Professor

Address: Head of the Physics Department, College of Science, University of Diyala

Date: / / 2022

Linguistic Amendment

I certify that the thesis entitled "Enhancement of Gas Sensing Properties of Metal Oxides Thin Films by Embedding of Noble Metals Nanoparticles " presented by (ASAAD AHMED KAMIL) has been corrected linguistically, therefore, it is suitable for debate by examining committee.

Signature: Name: Dr. Esam H. Hameed Title: Assistant Professor Address: College of Science, University of Diyala Date: / / 2022

Scientific Amendment

I certify that the thesis entitled "Enhancement of Gas Sensing Properties of Metal Oxides Thin Films by Embedding of Noble Metals Nanoparticles" presented by (ASAAD AHMED KAMIL) has been evaluated scientifically, therefore, it is suitable for debate by examining committee.

Signature:
Name:Dr. Bahjat B. Kazem
Title: Professor
Address: Dep. of Physics, College of Science, University of Al Mustansiriya
Date: / /2022

Scientific Amendment

I certify that the thesis entitled "Enhancement of Gas Sensing Properties of Metal Oxides Thin Films by Embedding of Noble Metals Nanoparticles" presented by (ASAAD AHMED KAMIL) has been evaluated scientifically, therefore, it is suitable for debate by examining committee.

Signature:

Name:Dr. Bushra K. Hassoon

Title: Professor

Address: Dep. of Physics, College of Education for pure Science (Ibn Al- Haitham), University of Baghdad

Date: / /2022

Examination Committee Certificate

We certify that we have read this thesis entitled " Enhancement of Gas Sensing Properties of Metal Oxides Thin Films by Embedding of Noble Metals Nanoparticles" presented by (ASAAD AHMED KAMIL) and as an examine committee, we examined the student on its contents, and in what is related to it, and that in our opinion it meets the standard of a thesis for the Degree of Doctor of Philosophy (Ph.D.) in Science of physics.

> Signature: Name: Dr.Nadir F. Habubi Title: Professor Date: / /2022 (Chairman)

Signature: Name:Dr.Sabah A. Salman Title: Professor Date: / /2022 (Member)

Signature: Name: Dr. Zaid T. Khodair Title: Professor Date: / /2022 (Member)

Signature: Name: Dr. Nabeel A. Bakr Title: Professor Date: / /2022 (Supervisor) Signature: Name:Dr.Abdul Hadi K. Judran Title: Professor Date: / /2022 (Member)

Signature: Name:Dr.Ammar A. Habeeb Title: Professor Date: / /2022 (Member)

Signature: Name:Dr.Tahseen H. Mubarak Title: Professor Date: / /2022 (Supervisor)

Approved by the Council of the College of Science:

Signature: Name: Dr. Tahseen H. Mubarak Title: Professor Address: Dean of College of the Science, University of Diyala Date: / /2022

Abstract

In this study, Au and Ag NPs were synthesized in distilled water by Pulsed Laser Ablation in Liquid (PLAL) technique using Q-switched (Nd:YAG) pulsed laser with laser parameters (520 mJ laser energy, 1064 nm wavelength, and 1Hz frequency). The effect of six different laser pulses (150, 250, 350, 450, 550, and 650) on the properties of these NPs were investigated systematically. ZnO and SnO₂ thin films were deposited on glass substrates by sol-gel spin-coating method. Volumetric ratios of ZnO and SnO₂ solutions with Au and Ag colloidal solution (3:2 and 4:1) were used to prepare ZnO and SnO₂ thin films embedded with Au and Ag NPs, and the morphological, structural, optical and Hall Effect properties of all the films were investigated. TEM micrographs of Au and Ag NPs shows that all samples were spherical in shape. The XRD patterns of the Au and Ag NPs exhibited the pure cubic crystalline structure at all the pulses used. The XRD patterns of Ag NPs also showed the formation of another cubic crystal structure attributed to AgO. FESEM images of the films exhibited spherical particles and randomly scattered spherical particles having irregular sizes for ZnO+Au (3:2) and ZnO+Au (4:1), respectively and showing cauliflower like shapes with irregular size-distribution for ZnO+Ag (3:2) and randomly scattered cauliflower particles having irregular shapes and sizes for ZnO+Ag (4:1). The images of SnO₂+Au (3:2) and SnO₂+Au (4:1) display that most of the particles obtained have spherical shapes and are agglomerated due to their small sizes. The XRD patterns of all ZnO thin films showed that the diffraction peaks belong to the hexagonal phase with a wurtzite structure, while the XRD patterns of all SnO₂ thin films exhibited diffraction peaks which belong to the tetragonal rutile crystal. Raman spectroscopy studies show that the peaks of ZnO and SnO₂ thin films embedded with Au and Ag NPs at volume ratio (3:2) are Raman-active peaks consistent vibration modes. It can be notice four typical peaks at Raman shift of 312, 453, 562 and 790

cm⁻¹ for (ZnO +Au) thin film and observed three peaks at 420, 560 and 825 cm⁻¹ are the transverse optical (TO), longitudinal optical (LO) polar branches, respectively for (ZnO +Ag) thin film. Also, show two of the four fundamental Raman-active peaks at 751 and 807 cm^{-1} for (SnO₂+Au) thin film and five peaks at 237, 421, 473, 561and 749 cm^{-1} for (SnO₂+Ag) thin film. The absorbance values of the films decrease with the increase of wavelength, it is increase as the molarity of ZnO and SnO₂ increases. It can be notice that the absorbance increase with the volumetric ratios of ZnO and SnO₂ thin films embedded with Au and Ag NPs increasing. The absorption coefficient of ZnO and SnO₂ thin films embedded with Au and Ag NPs at different volume ratios (3:2 and 4:1) increase gradually with the increase in the energy of the incident photons until it reaches the value of 10⁴ cm⁻¹, the values of the absorption coefficient greater than 10⁴ cm⁻¹ indicate the possibility of allowed direct electronic transitions. The value of optical energy gap of ZnO and SnO₂ thin films embedded with Au and Ag NPs at different volume ratios (3:2 and 4:1) obtained are (3.92, 3.90, 3.99 and 3.97 eV) and (3.56, 3.58, 3.80 and 3.85 eV), respectively. Hall Effect measurements of ZnO thin films embedded with Au and Ag NPs show that the conductivity increases as carrier concentration increases. It can be notice that the resistivity decreases as carrier concentration increases for AuNPs embedded with ZnO, while it is increases for AgNPs embedded with ZnO. The measurements of SnO₂ thin films embedded with Au and Ag NPs show the conductivity increases as carrier concentration decreases, and the resistivity is decreases at a high amount of Au and Ag. Gas sensor results show that the maximum sensitivity of (SnO_2+Au) sensor to 60 ppm of NO₂ gas is greater than (ZnO+Ag) sensor. The results show the sensitivity increase as the operating temperature and as the concentration of the NO₂ and NH₃ gas increases. Also can be notice that the response and recovery times decrease as the operating temperature increases.

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| List of | Symbols |
|---------|----------------|
|---------|----------------|

| Symbol | Meaning | Unit |
|-------------------|--|--------------------|
| Å | Angstrom | |
| θ | Diffraction Angle | Degree |
| hv | Photon Energy | eV |
| t | Thickness | nm |
| α | Absorption Coefficient | cm ⁻¹ |
| a, b, c | Lattice Constants | Å |
| hkl | Miller Indices | |
| Dav | Crystallite size | nm |
| dhkl | Interplanner Spacing | Å |
| β | full width at half maximum | Rad |
| M,M _{wt} | M the molar concentration, M_{wt} the molecular weight of the material | Mol (g/mol) |
| N | Number of crystallites per unit area | cm ⁻² |
| δ | Dislocation Density | cm ⁻² |
| S | Micro Strain | % |
| Io | incident light intensity | mW/cm ² |
| Ι | penetrating light intensity | mW/cm ² |
| Eg | Energy gap | eV |
| Ev | Valence band energy | eV |
| Ec | Conduction band energy | eV |
| λ | Wavelength of incident light | nm |
| h | Planck's constant | J.s |
| n* | Refractive index | - |
| Т | Transmittance | - |
| Α | Absorbance | - |
| R | Reflectance | - |

| A'and B | Constants depending on properties of bands | - |
|----------------|--|-------------------|
| υ | Frequency | s ⁻¹ |
| Т | The Absolute Temperature | k |
| Bz | Magnetic Field | Tesla |
| $\mu_{ m H}$ | Hall mobility | $m^2/(V.s)$ |
| R _H | Hall coefficient | m ³ /C |
| V _H | The Hall Voltage | Volt |
| n | The Carrier Concentration | Cm ⁻³ |
| р | The Hole Concentration | Cm ⁻³ |
| σ | Conductivity | $(\Omega.m)^{-1}$ |
| ρ | resistivity | (Ω.m) |
| σ。 | minimum electrical conductivity at 0 K | $(\Omega.m)^{-1}$ |
| e | The Electron Charge | С |
| S | Sensitivity | |
| Ra & Rg | Ra the resistance in air and R_g is the resistance in presence of test gas | Ω |
| ppm | parts per million | mg/L |

List of Abbreviations

| Abbreviation | Description |
|--------------|---|
| UV-Vis | Ultra Violet Visible |
| IR | Infrared |
| XRD | X- Ray Diffraction |
| FESEM | Field Emission Scanning Electron Microscopy |
| TEM | Transmission Electron Microscopy |
| SEM | Scanning Electron Microscope. |
| EDS | Energy Dispersive X-ray spectroscopy |
| D.C | Direct Current |
| MOS | Metal Oxide Semiconductor |
| NPs | Nanoparticles |
| C.B | Conduction Band |
| V.B | Valance Band |
| W-H | Williamson-Hall |
| SRO | Short Range Order |
| LRO | Long Range Order |
| SPR | Surface Plasmon Resonance |
| Nd:YAG | neodymium doped yttrium aluminum garnet |
| PLAL | Pulsed Laser Ablation in Liquid |
| PLA | Pulsed Laser Ablation |
| SAED | Selected Area Electron Diffraction |
| AAS | Atomic Absorption Spectroscopy |
| CVD | Chemical Vapor Deposition |
| LED | Light-Emitting Diode |

| LDs | Laser Diodes |
|-------|--|
| APCVD | Atmospheric Pressure Chemical Vapor Deposition |
| VOC | Volatile Organic Compound |
| XPS | X-ray Photoelectron Spectroscopy |
| AES | Auger Electron Spectroscopy |

Chapter One

Introduction

and

Previous Studies

1.1 Introduction

The term "thin films" refers to a layer or layers of atoms having a thickness of less than 1µm (1000 nm). One of the most recent technologies to be fully determine is the thin film technology .Importantly advances research on semiconductors and metals by clearly indicating their chemical and physical properties. Thin films' characteristics typically differ from those of the bulk due to their two-dimensional nature [1]. In bulk, forces acting in all directions are in charge of the particles. In contrast, these forces have an impact on the particles that are on the surface of thin films. Depending on the nature of the research area or other practical applications, the film layer is deposited on specific substrates such as glass slides, silicon wafers, aluminum, and quartz. Currently, thin films have many electronic and optical applications. The electronic applications of thin films have steadily increased over the past decades. This can be due to their wide uses in manufacture of electrical resistors, capacitances, transistors, integrated circuits for digital computers and other electronic devices. In addition, thin films are particularly important in a wide range of optical industries such as development of ordinary and thermal mirrors, high-reflectance mirrors, and semi-transparent reflectance coatings which is used in optical equipments (e.g. filters in solar cells and non-absorbent materials used in interference) [2].

1.2 Thin Films Deposition Techniques

As seen in Figure 1.1 [3] the approaches for the deposition of thin films can be split into two main primary categories: physical and chemical techniques.



Figure (1.1): Classification of thin film deposition techniques [3]

1.3 Metal oxides

Compounds made up of metal atoms and oxygen are called metal oxides. Most metals exist as native metal oxide deposit in nature. Aluminum oxide, for example, accounts for 8.1 have percent of earth's crust. The use and application of thin metal oxide films has been known for a long time, but the demand is still growing. Metal oxides are really prevalent because

electronegative oxygen atoms and the metal have created stable chemical interactions.

Metal oxides are used as capacitors, transistors, computer memory,

and other components in semiconducting materials, especially in the microelectronics industry. In order to increase durability and create coatings for energy-efficient glass installations with low emissivity, metal oxide thin films are frequently employed as practical glass coatings [4]. The production and characterisation of thin films with particular(SnO_2 and ZnO) nanostructures have been produced for gas sensing [5].

Metal oxide gas sensor is made up to interact with a certain group of gases, where they go through an oxidation or reduction process. This technique causes the target gas to exchange an electron with the metal oxide sensors at a specific characteristic rate. This will affect the resistance of the sensor and producing a specific signal. The gas sensor devices provide a range of different features, like small design, low cost, ease of production, simplicity of measurement, and reliability. The theory of metal oxide sensor activity is based on the change in oxide conductivity due to gas contact which is usually proportional to the gas concentration [5,6]. Two kinds of metal oxide sensors are commonly available; n-type (zinc oxide, tin dioxide, iron (Fe_3O_2) oxide) or titanium dioxide, responding to gas reduction and p-type (nickel oxide, cobalt oxide) reacting to oxidizing gases [7].

Transparent Conducting Oxides (TCOs) are metal oxides with high optical transmittance and high electrical conductivity. They are also referred to as wide-band gap oxide semiconductors.

1.3.1 Tin oxide (SnO₂)

Tin oxide exhibits a tetragonal rutile structure can be seen when its lattice parameters of a=b = 4.737 and c = 3.826 Å, and $\alpha = \beta = \gamma = 90^{\circ}$. The unit cell has two tin atoms and four oxygen atoms. Six oxygen atoms are joined to each tin atom in the corners of a regular octahedron. At the corners

three tin atoms of an equilateral triangle surround each oxygen atom [8], as shown in Figure (1.2).



Figure. (1.2): The lattice tetragonal rutile structure of $SnO_2[8]$.

The tin chemistry consists of the metal's oxidation number with oxidation states of +2 or +4. These oxidation states are controlled by tin (II) oxide, commonly known as stannous oxide, and tin (IV) oxide, also known as stannic oxide. Sn (II) and Sn (IV) in a variety of oxidation states make up the transitional phases Sn_2O_3 and Sn_3O_4 [9]. Due to their distinct structural and electrical characteristics, SnO and SnO₂ have a variety of applications [10]. Tin oxide (SnO_2) films are n-type semiconductors with a wide band gap in the range of (3.6 and 4.3 eV). SnO_2 semiconducting transparent thin films have a number of attractive properties for technical applications in "solar energy conversion, flat screen displays, electrochromic devices, invisible security circuits, LEDs and gas sensors", etc. As a result, the creation of large area SnO₂ films on effective and cheap accessible substrates is of great interest. SnO₂ is a basis in sensors for flammable gases, such as carbon monoxide detectors. In this instance, the sensor surface is heated to a constant temperature, and when a flammable gas is detected, the electrical resistance decreases. [11]. Table (1.1) shows some properties of SnO₂.

| Properties | Values |
|---------------------------------------|---|
| Molar Mass | 150.71 g/mol |
| Appearance | White or light grey powder |
| Density | 6.86 g/cm^3 |
| Melting point | 1630 ⁰ C |
| Band gap | (3.6-4.0) eV, direct |
| Magnetic susceptibility (χ) | 4.1 x 10 ⁻⁵ cm ³ /mol |
| Refractive index at wavelength 550 nm | 2.006 |

Table 1.1: some properties of SnO₂ [8].

1.3.2 Zinc oxide (ZnO)

Zinc oxide (ZnO) has been studied for several decades as an effective semiconductor. One of the most interesting sensor materials is ZnO, which combines unique optical and electrical characteristics. ZnO is a unique substance with a variety of piezoelectric, pyroelectric, and semiconducting properties. ZnO crystal structures: zinc blende and hexagonal (wurtzite). Has some advantages, it is an n-type semiconductor with a direct wide band gap (3.3 eV) and a strong excitation binding energy (60 meV) [12]. It is an essential functional oxide, displaying high conductivity and near ultraviolet emission. Also, ZnO demonstrates a piezoelectric effect, a key feature in the construction of electromechanical-coupled sensors and transducers. ZnO is a water-insoluble white powder and commonly used as an ingredient in many materials and products, glass, cement, lubricants, paints, ointments, adhesives, sealants, pigments, foods and batteries, ferrites, fire retardants, and first aid tapes, materials, rubbers, plastics, ceramics and high-technical applications such as surface acoustic wave filters, photonic crystals, photodetectors, light emitting diodes, photodiodes, optical modulator waveguides, solar cells, varistors, and laser diodes (LDs) provide a broad range of ZnO nanostructures. The advantages of this semiconductor nanostructure included high band gap, clear luminescence at ambient temperature, high electron mobility, and excellent clarity. [13,14]. Figure (1.3) shows the ZnO crystal structure [14], and table 1.2 depicts some properties of ZnO [15].



Figure (1.3): ZnO crystal structures:Zinc blende and Hexagonal(wurtzite)[14].

| Chemical formula | ZnO | |
|-----------------------------|---|--|
| Molar mass | 81.406 g/mol | |
| Appearance | White solid | |
| Density | 5.61 g/cm ³ | |
| Melting point | 1975 °C | |
| Band gap | (3.2-3.4) eV, direct | |
| Magnetic susceptibility (χ) | $-27.2 \ 10^{-6} \ \mathrm{cm^{3}/mol}$ | |
| Refractive index | 2.029 | |

Table 1.2: Some properties of ZnO [15]

1.4 Nanotechnology

The word 'Nanotechnology' was used and characterized early in 1974 by Taniguchi [16]. In addition, the US National Nanotechnology Initiative (NNI) in 2000 as provided by the concept of nanoscience and nanotechnology [17]. The word "*Nano*" refers to 10^{-9} meter is used to describe the materials smaller than the molecules, clusters of atoms or particles in the quantum world [18]. The word "colloid" is more elusive and can vary from nanometers to several hundred micrometers in particle size. Since about the beginning of humanity, people have been attracted by the vibrant colours of noble metals like gold or silver. Additionally, to being applied as a medical substance to treat arthritis, they have been used to colour glass and textiles. Devices that can be used in a variety of physical processes are made using Au colloidal surface-enhanced Raman spectroscopy, solar cells. (e.g. sensors. optoelectronic devices); biological (e.g. drug delivery systems); and biomedical (e.g. diabetic healing, Photothermal therapy, biochemical sensors) applications [19-28].

1.5 Nanoparticles Synthesis Methods

1.5.1 Top-down method

The top-down approach usually includes laser ablation, starting from bulk. Basically, This method involves separating a system into its constituent elements. In order to get smaller parts, this method also uses cutting, milling or drilling equipment. It can be used to classify micro-patterning processes including photolithography, plasma etching, and laser ablation. Top down approaches are suffering from the need to reduce huge quantities of material [30].

1.5.2 Bottom-up method

Smaller elements are combined into larger structures using the bottomup process. To obtain biotechnological elements, single molecules are combined using the bottom-up method. The self-assembly of atoms and molecules is a term used in nanotechnology to describe how larger structures are produced. This form includes the sol-gel method as well as chemical vapor deposition (CVD). [30].

1.6 Definition of Nanoparticles

The word nanoparticle refers to a small particle that ranges between 1 to 100 nanometres in size in three dimensions, made up of a very small number of atoms or molecules, It take a variety of shapes, including spherical, triangular, cubical, pentagonal, rod-shaped, shell-shaped, ellipsoidal, etc.etc. [18]. Due to their high surface area and high degree of electronic conductivity properties, nanoparticles have unusual chemical and physical properties compared to their heavy bulk materials [31]. According to their chemical, physical and biological properties, the metallic nanoparticles are major subjects of research in modern materials science. Noble metal nanoparticles of silver and gold are of particular interest [32].

1.6.1 Noble Metal Nanoparticles

Noble metal such as silver and gold NPs have attracted a great attention because of the special electrical, optical, physical, chemical, and magnetic properties [33]. In the green and red regions of the UV-visible spectrum, both Au and Ag NPs have a plasmonic effect due to the dispersion and absorption of photons. They have stable chemical, physical and biological properties, such as resistance to high temperatures, photo-irradiation, high resistance to oxidation or acids, and catalytic action and properties of biocompatibility. Ag NPs have been used extensively as nanoscale sensors, catalyze, optical data storage anti-bacterial agents in the health industry, food storage, textile coatings and a number of environmental applications. Furthermore, it could be potentially used as biological labels and electroluminescent displays [34].

Au NPs have many different applications depending on the size of particles. For example, in immune histochemistry, microscopy (light and high magnification TEM) and biomarkers, the small sizes of Au NPs (2 nm-15 nm) are used. In environmental detection and purification, drug distribution, biomarkers, chemical sensors and DNA detection, medium size Au NPs (20-60 nm) are used. Large Au NPs (80 - 250 nm) are used in forensic science, computer devices, optical mammography, manufacturing, etc. [34]. Ag and Au nanoparticles are chemically stable and often display surface enhanced Raman scattering in the visible wavelength range, where they can greatly enhance various optical cross-sections. Table 1.3: show the physical properties of Au and Ag noble metals.

| property | Gold | Silver |
|--|---------|--------|
| symbol | Au | Ag |
| Atomic Number | 79 | 47 |
| Atomic Mass (U) | 196.97 | 107.87 |
| Melting Point(°C) | 1064.18 | 961.8 |
| Boiling Point(°C) | 2970 | 2162 |
| Density g/cm ³ | 19.32 | 10.50 |
| Electrical Conductivity $(10^6 \Omega^{-1}.m^{-1})$ | 0.442 | 0.630 |
| Thermal Conductivity (W.m ⁻¹ .k ⁻¹) | 318 | 429 |
| Refractive Index | 0.20 | 0.135 |

Table 1.3: physical properties of Au and Ag noble metals.

1.6.2 Nanoparticles preparation techniques

There are many techniques that can be used to prepare nanoparticles, including as photo-reduction, flame metal combustion, electrochemical reduction, solvothermal electrolysis, chemical fluid deposition, and spray pyrolysis. Metal salts are often reduced chemically in the presence of enabling molecules to produce noble metal nanoparticles. Additionally, the top-down generation of NPs is now frequently done by pulsed laser ablation in liquid (PLAL). The relatively new PLAL technique was initially presented in 1993 by "Fojtik" et al. [35]. It has attracted attention as a top-down methodology of operation. Different processes have been used to synthesize nanoparticles of silver and gold. Nanoparticles have been produced by biological, physical, and chemical processes. Figure (1.4) show the different methods for the synthesis of nanoparticles [36].



Figure (1.4): Different methods for the synthesis of nanoparticles [36].

1.7 Pulsed Laser Ablation (PLA) Method

Pulsed laser can be used to vaporize the plume of material that tightly restricted of both temporally and spatially, this method can be used instead of simply evaporating material for the production of vapor supersaturated [36]. Laser ablation is convenient method to generate nanoparticles from the gas phase [37]. In other words, PLA method can only fabricate little quantities of nanoparticles. PLA technique can control the size distribution and maintain the purity of the crystal such as Si nanoparticles [38]. PLA method can be used to vaporize materials that are difficult to evaporate by other methods [36].

Basically, in pulsed laser ablation process, the beam of pulsed laser is focused onto target (target in solid phase), then the target is partially evaporating with each laser pulse [37]. The target is usually rotated with each new pulse of laser because the rate of material removal by laser ablation decreases with longer target exposure time [39]. Laser such as Nd:YAG with wavelength (1064 nm and/or 532 nm) is usually used as a pulsed laser source in the PLA process [36]. When the surface of target is hit or shot by laser beam, the interaction happened between the surface of target and laser beam. Surface of the target is heated much higher than the boiling point of target material to be in the vapor phase. This vapor becomes superheated and ionized leading to form a plasma phase. Carrier gas (inert gas) flowing on the heated surface target cools the vapor and carries nanoparticles away from the area of laser ablation [37]. Schematic examples of main elements of the pulsed laser ablation mechanism are shown in Figure (1.5), where (a) depicts the initial laser radiation absorption (depicted by long arrows), the start of melting and vaporization (shaded area indicates melted material, short arrows indicate motion at the solid-liquid interface), and (b) illustrates how the melt front spreads into the solid, continuing vaporization, and becoming important by the start of laser-plume interaction., (c) suggests the absorption by the plume of incident laser radiation and the production of plasma, and finally (d) indicates that the front of the melt recedes, contributing to subsequent resolidification [40].



Figure (1.5): Schematic illustrating key elements of the PLA process [40].

Now the beam of a pulsed laser onto a target material under low pressure or vacuum, it should be noted of background gas or in liquid such as water or ethanol solutions [40]. The following list of elements, which can influence and regulate particle size, can be used to describe them. [41]

- a) The Laser parameters: fluence, wavelength and pulse duration parameters.
- b) The ambient gas conditions: type of liquid pressure, nature and flow parameters.

1.7.1 Pulse Laser Ablation in Liquids (PLAL)

A promising top-down method for managing the production of nanomaterials is pulsed laser ablation in liquid media (PLAL), where ablated molecules are rapidly responsively quenched at the plasma-liquid interface. Noble metals, alloys, oxides, and semiconductors can all be deposited using the easy PLAL technique. It can create nanoparticles without counter-ions or surface-active materials, making it simple and without constraints. A metal target is exposed to a high-power pulsed laser beam that creates a local plasma with a high temperature (about 6000 K) and high pressure at the solidliquid interface [42-44]. The Pulse Laser Ablation in Liquid method has many advantages, such as:

- 1- Simple and easy experimental setup.
- 2- Low cost because it does not always need a vacuum chamber.
- 3- Environmentlly friendly because no toxic or dangerous gases are released.
- 4- We are able to make pure NPs colloid devoid from impurities [45].
- 5- This technique can use a variety of liquids and targets and is quick.
- 6- NPs can be produced without the need for heat treatment because the confinement effect causes the temperature and pressure of the plasma created by the pulse laser to be much higher than those of a vacuum or a gas on the target surface immersed in liquid. Figure (1.6) shows a schematic diagram of the experimental setup of laser ablation for synthesis nanoparticles from solid target immersed in aqueous solution. A lens is often used to focus the Nd-YAG laser beam onto a metallic target. The target is fixed by a holder at the bottom of a quartz container [46].



Figure (1.6): A schematic diagram of the experimental setup of laser ablation [46].

1.8 Spin coating technique

Spin coating method is an essential technique used in development and deposition of organic and inorganic thin films [47]. Films that produced by this method are highly reproducible and homogenous. During spin coating process, two forces are acting on the solution; the adhesive forces at the solution substrate interface and the centrifugal forces resulting from the highspeed rotation. These competing forces will cause a strong shearing action at the interface which could lead to form a thin film with adjustable thickness depending on the angular velocity, solution concentration and the viscosity. There are several critical factors in homogeneous films production, such as solvent evaporation rate, fluid viscosity, solution concentration, angular velocity (rotating velocity) and spinning time [48]. The liquid is first placed onto the substrate in the "spin coating process", and then the substrate is accelerated to the spinning speed that was designed for it. A minute quantity of film is absorbed by the substrate as a result of the motion caused by centrifugal force [49]. The effect of gravity force on the spin coating can be traditionally ignored, as the formation of thin film under spinning dominates the substrate adsorption.

speed in spin coating is one of the most essential factors. The speed of the substrate affects the radial (centrifugal) force applied to the liquid as well as the speed and usual turbulence of the air immediately above it [50]. The force imparted to the fluid solution as it approaches the substrate's edge must be balanced with the rate of drying, which impacts viscosity, to determine the film thickness. Additionally, the substrate's acceleration toward the maximum spin speed may have an effect on the properties of the coated film. Acceleration must be precisely controlled since the solution starts to dry during the early portion of the spin cycle. The coat characteristics of patterned substrates are also significantly influenced by acceleration [51].

1.9 The sol-gel method

sol-gel techniques combine a variety of techniques for creating materials from solutions, and one of its processing steps involves the formation of gel, sol-gel is a chemical techniques that are used to form colloidal oxides either from chemical solution or from colloidal particles of nanostructure. The most prevalent kind of sol-gel synthesis relies on controlled chemical hydrolysis [52]. The polycondensation and hydrolysis process that occurs during the first stage of this process result in the synthesis of an initial colloidal solution, also referred to as a sol of hydroxide particles with a size in the nano range. The applications of sol-gel process are many. One example is the use of metal-organic or inorganic material as precursors in sol-gel method to create thin film coatings [53].

Centrifugal of gravitational exhaustion is used to create thin films, which determines the form of the fluid outline, the magnitude of the forces acting on the solid phase, and the time of the deposition process. This is followed by continuous stirring and drying. This method allows to get of the materials at low temperatures. It is an ideal technique for preparing thin films, nanotubes, powders and fibers. Figure (1.7) represent Sol gel process steps for synthesizing thin films and powders [54,55].



Figure (1.7): Steps for preparation of thin films and powders by the sol gel process [54].

1.10 Previous Studies

In 2010, Gupta et al. developed a variety of ZnO nanostructures, such as nanowires and nanobelts, to prepare thick films (with variable grain boundaries) and isolated nanowire/nanobelt gas sensors. Sensors for H₂S and NO gases were tested for their sensitivity. They found that both intragrain resistances and grain boundaries get a factor in the NO gas reaction, grain boundaries alone are responsible for the response of ZnO sensors to H₂S gas. Additionally, thay discovered that the sensors built using isolated nanobelts responded to NO with a very specific set of characteristics [56].

In 2010, Ahpark et al. manufactured SnO_2 -ZnO hybrid nanofibers by using the pulsed laser deposition and electro spinning techniques. After calcination

at 600 °C, SnO nanocrystalline coated ZnO nanofibers with a random network topology were produced. SnO₂ deposit had a fiber diameter of 55–80 nm and a size of 10-15 nm, respectively. At a temperature of 200°C , the sensor that was composed of SnO2-ZnO hybrid nanofibers demonstrated a very strong gas response to concentrations of NO2 as low as 400 parts per billion [57].

In 2010, Qunxiang et al. synthesized Ag nanoparticles embedded-ZnO nanorods by photochemical method. TEM, XPS, DSC, XRD, and SEM were used to characterize the samples after they were prepared. The characterization results showed that ZnO nanorods included Ag nanoparticles that had been enclosed within them. Additionally, the properties of Ag NPs inserted in ZnO nanorods for gas sensing were studied. The response of Ag NPs embedded-ZnO nanorod sensors to 50 ppm ethanol was almost identical to that of sensors made from pure-ZnO nanorods, given the possibility of improving the efficiency of the sensors by including Ag NPs into the surfaces of ZnO nanorods. It was discovered that the Ag NPs embedded-ZnO nanorod good stability and significantly improved gas-sensing had sensors performances in their response and selectivity for detecting ethanol vapor. [58].

In 2012, Enrico et al. fabricated 40–50 nm thickness of NiO and ZnO thin films with inserted Au nanoparticles by the sol–gel technique. The films made of nanocomposites are crystalline and porous, and the optical absorption in the visible range depends on the concentration of gold nanoparticles. These films were studied as a possible optical and electrical sensor for the detection of polluting gases. It has been determined that H_2 , CO, and NO₂ all have a rapid response. The optical characteristics is considering the sensing of both NiO and ZnO films over the gold surface plasmon resonance peak wavelength spectrum have been found to be enhanced by gold nanoparticles. Additionally, the optical response of ZnO was improved by the presence of Au, even though Au NPs are optically inactive in this range. In addition, It was shown that the reducing gases inject electrons into the oxide, and that Au nanoparticles immediately detect the charge variation by combining the observed shift in the surface plasmon resonance peak with the different semiconductive types of the two oxides [59].

In 2012, Vural synthesized awide variety of NPs by PLAL, including magnetic nanostructures, semiconductors, nanoalloys, noble metals, base metals, and core-shell nanostructures. It was reported that PLAL could synthesize Au, Ag, and Pt NPs in a variety of liquid environments using a Nd: YLF laser (Q-Switched Laser, 527 nm wavelength, 16 W average power, 110 ns pulse duration, and 16 mJ pulse energy for 1 kHz). First, nanoparticles of silver, gold, and platinum have been produced in deionized water using a pulsed Nd: YLF laser. Second, similar conditions were used to manufacture these NPs in methanol. After that, transmission electron microscopy, scanning electron microscopy, X-ray photoelectron spectroscopy, X-ray diffractometer, and UV-Vis Photospectrometer analysis techniques were used to characterize the colloidal NP solutions. A UV-Vis photospectrometer and transmission electron microscopy were used to analyze the Au and Ag NPs after they had been incorporated in nanofibrous composites [60].

In 2013, Niranjan and Gupta developed ethanol sensor using hydrothermally produced zinc oxide (ZnO) nanowires modified with a thin layer of Au (~10 nm). At an operating temperature of 325 °C, the sensor films respond most effectively to the presence of ethanol. The response and recovery times for Au modified sensor films towards 50 ppm of ethanol at 325 °C were 5 and

20 s, respectively. The addition of Au not only improved the reaction kinetics toward ethanol but also improved the sensor response. This improved sensing performance according to the electronic sensitization process and the nano-Schottky barriers type connection between Au and ZnO were the causes of the faster reaction kinetics [61].

In 2013, Machmudah et al. produced a silver and gold nanoparticles used PLA in pressured CO_2 . Under different pressures, 532 nm laser ablation was utilized as the excitation wavelength. The variations in CO_2 density and the lengthening of the ablation duration both had a substantial impact on the architectures of Au and Ag nanoparticles. A network structure of smaller gold particles was created, as evidenced by a field-emission scanning electron microscopy (FE-SEM) image of the gold nano-structured particles on silicon wafer. The following could be seen as the nanoparticle production process: During the ablation process, the larger gold/silver particles were melted, and the smaller, spherical nanoparticles that were expelled from them formed nanoclusters were connected to the molten particles [62].

In 2015, Rajesh et al. used ZnO nanoparticles to establish NO₂ gas sensors. A variety of ZnO nanomaterials, including thin films, nanosheets, quantum dots, nanorods, nanowires, and nano-micro flowers, were employed in the fabrication of NO₂ gas sensors. The fundamental characteristics of gas sensors, including recovery time, reaction time, selectivity, limit detection, gas response, stability, and recyclability, etc. were explored. The effects of several variables on the NO₂ gas sensing characteristics, including the concentrations of NO₂, the annealing temperature (T), the morphologies and particle sizes of ZnO, the relative humidity, and the operating temperatures, were also discussed [63].

In 2015, Tharsika employed a single-step thermal evaporation process with carbon assisted to make ZnO and SnO₂ nanostructures with various morphologies, and investigated into their gas sensing capabilities. Tin oxide, zinc oxide, and carbon powders made up the source material, which was combined and placed into a quartz boat before even being put in the center of a tube furnace. Nanostructures were studied using (XRD), (FESEM), (TEM), and (EDS) to determine their crystallographic phase, microstructure, and elemental composition. In the hierarchical nanostructures, ZnO branches took on a hexagonal shape as they developed on the ZnO shell layer. With short response and recovery durations, The sensitivity and selectivity of Zn₂SnO₄ nanowire-based sensors for ethanol were excellent. Ethanol concentrations as low as 20 ppm can be detected by SnO₂ core/ZnO shell hierarchical nanostructures at 400 °C was five times greater than that of pure SnO₂ nanowires after 90 minutes of deposition. Highly active sensing was suggested to be responsible for this increase in ethanol sensitivity [64].

In 2016, Li et al. manufactured modified ZnO (Au/ZnO) NPs using a "bamboo cellulose template and the calcination" method. They studied the gas-sensing capabilities of Au/ZnO NPs -based sensors. Comparing the Au/ZnO NPs to pure ZnO, the results showed an improvement in gas sensing performance. The Au/ZnO NPs responded about 2.7 times more effectively to 100 ppm ethanol (50) at 240 °C than they did to acetone., indicating a stronger selectivity for ethanol. This high reaction to ethanol may be caused by the small size, Schottky barrier, and catalysis [65].

In 2016, Aled et al. developed a simple chemical process that allowed them to create highly sensitive gold nanoparticle coated (decorated) zinc oxide nanosheet gas sensors. These sensors were able to provide a normalized current gain of 2.54 (at 10V) in dry air that contained 2.5ppm of hydrogen gas

while being heated to 200 degrees Celsius. Gold nanoparticles having a mean diameter of 5 nm were used in a straightforward "microwave-assisted hydrothermal" growth approach to bring up the formation of zinc oxide nanosheets. At a temperature of 200 degrees Celsius, a response of 1.24 was obtained for concentrations of ppm less than 125 when compared to sensors based on undecorated sheets [66].

In 2017, Borhaninla et al. created varying concentrations of gold nanoparticles combined with tin dioxide nanoparticles in the laboratory, and then studied the CO sensing characteristics of the resulting compounds. For the preparation of the first solution, the sol-gel method was utilized. For the purpose of characterizing the nanoparticles, XRD, SEM, TEM, DLS, and spectrophotometry were utilized. At an operational temperature of 340 degrees Celsius, the pure sensors exhibited a response of approximately 4 to 12.8 for $(20-80 \text{ s}) \times 10^{-6} \text{ CO}$. At a concentration of 50 s×10⁻⁶ CO, the reaction time is approximately 10 seconds, and the recovery time is around 14 seconds [67].

In 2017, Sonik et al. The production of zinc oxide (ZnO) nanoparticles was carried out by using a combination of two distinct processes: thermal evaporation in a two-zone furnace and simple heat treatment. As a film that was deposited on glass substrate, Zn acetate dihydrate at concentration of 0.17 M was used for both of these processes. The XRD, FESEM, FTIR, and UV–Vis spectrophotometers , as well as the LCR meter, were utilized in order to characterize the ZnO that was synthesized. The results of the XRD analysis showed that the wurtzite crystals had a hexagonal structure with a preferential orientation along the (101) plane. According to the findings of FESEM, the grain size was in the region of 50 to 5 nm. After looking into the optical properties, researchers came to the conclusion that the band gap can be found

in the range of 3.32–3.36 eV. At an operating temperature of 250 degrees Celsius, the gas sensing properties demonstrated a higher response in the case of thermal evaporation in comparison to a typical heat treatment [68].

In 2017, Roberto et al. created an ether gas-sensor and also relies on gold nanoparticles (Au NPs) that are coated zinc oxide microstructures. Measurements taken using a "scanning electron microscope (SEM) and a high-resolution transmission electron microscope (HRTEM) were used to investigate the structural and morphological properties. In a relatively low temperature range, the response of gas sensing was studied, with a range that between 150 and 250 °C. When compared to a sensor that was made from pure ZnO. The sensor's ether gas response was noticeably better at the highest possible working temperature when it was constructed on Au NPs coated ZnO. In point of fact, a sensor entirely built on ZnO demonstrated only a rather low sensitivity of roughly 25 percent [69].

In 2017, Sachin et al. Utilizing tin oxide (SnO_2) thin film by a conventional spin coating sol-gel process with $SnCl_4.2H_2O$ as a precursor. XRD, SEM, TEM, FTIR, PL, and UV-Vis" techniques were used to examine the film's optical, electrical, structural, and gas sensing characteristics. The samples had a tetragonal rutile structure, according to XRD and Transmission Electron Microscopy, which revealed that the average particle size was approximately (11.26)nm. At various operating temperatures and concentrations, ethanol gas sensing of manufactured SnO_2 thin film was evaluated [70].

In 2018, Gisane et al. synthesized ZnO nanorod-Au nanoparticle hybrids on a substrate. In order to be utilised in gas sensor devices, ZnO nanorods were grown on Al_2O_3 substrates at low temperatures by chemical bath deposition. A sputtering process was then used to deposit Au NPs. The studies from

SEM, XRD, EDX and TEM indicated that the Au NPs uniformly covered the ZnO nanorods surface and that the hexagon-based ZnO nanorods grew perpendicularly to one another on the substrate. When compared to ZnO nanorods at 300 oC, the ZnO-Au NPs hybrid-based sensor showed an enhanced sensor response for H_2 and O_2 gases [71].

In 2018, Shano prepared PAni NFs and copper nanostructures [CuO and tin oxide (SnO₂)] used the hydrothermal process and spin coating at room temperature to deposit PAni NFs, CuO, SnO₂, and their composites on glass and silicon substrates with a thickness of nearly 325 nm. For inorganic - polyaniline films, the surface morphological, optical, structural, electrical, photoconductivity, and gas sensing properties have been investigated. The XRD results reveald that the PAni films are naturally crystalline, and that the composites of PAni/SnO₂ and SnO₂ nanostructures are polycrystalline and have tetragonal structures. The sensitivity to H₂S gas was increased with the increase in the operating temperatures and SnO₂ and CuO concentration. The highest H₂S gas sensitivity to nanocomposites PAni/CuO films was obtained at high CuO concentrations and was determined to be 260 % at (To= 200 °C). The recovery times and response increased as operating temperature increased, showing a quick response time (0.753 s) and recovery time (0.787 s) at (30°C)[72].

In 2018, Ganesh et al. Ag/ZnO composite nanostructures with high sensitivity ammonia gas sensor were used, and their optical, morphological, structural, and gas sensing characteristics were investigated. STEM examination clearly showed that the Ag/ZnO composite had a flower-like shape. Ag, Zn, and O were evenly distributed, according to STEM-mapping measurements. According to the ammonia gas sensing analysis, the Ag/ZnO (6 wt%) showed

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a greater gas response than other Ag wt% contents. The maximum response was 29.5 when Ag/ZnO (6 wt%) was treated to 100 ppm ammonia gas [73].

In 2019, Saleh synthesized ZnO and SnO₂ nanostructures thin films on glass substrate by hydrothermal drop casting techniques and atmospheric pressure chemical vapor deposition. Tin chloride, zinc acetate, zinc nitrate and hexamethylenetetramine (HMTA), were used in this process. The atmospheric pressure chemical vapor deposition (APCVD) system was used to obtain the optimized thin films by taking appropriate deposition conditions, such as substrate temperature, flow rate of gas, quality and location of deposition within the system reactor. The morphology, structural, surface roughness and optical properties were studied by (XRD), (FE-SEM), (EDS), (AFM), UV-Vis spectroscopy, respectively and gas sensing properties have been investigated for (SnO₂ and ZnO) thin films. X-ray diffraction (XRD) analysis was performed for all samples prepared at different substrate temperatures (300, 400, 450, 500, 550 and 600°C) and different oxygen gas flow rates (4, 5, 6, and 8 NL/h). It was observed that by increasing the oxygen flow rates and substrate temperatures, the crystallite size increased [74].

In 2019, Chen et al. by using a one-pot hydrothermal process, ZnO nanowires/Au NPs and ZnO nanowires hybrid (Au-ZNWs) with different concentrations of Au were produced and examined by SEM, XRD, XPS, TEM, and FTIR. Structure-characterisation results showed that Au nanoparticles had self-assembled on the surface of ZNWs. According to gas sensing properties, 1 mol % Au-ZNWs had the best sensing results when compared to pure ZNWs and Au-ZNWs" with various Au concentrations. At 150 °C. The greatest response of 1 mol% Au-ZNWs to 1 ppm NO₂ was 31.4, which was more than 4 times the 8.2 of pure ZNWs. Compared to pure ZNWs with different concentrations of Au exhibited higher selectivity to NO₂ [75].

In 2019, Mohamedkhair et al. fabricated silver nanoparticles with Tin oxide films as H_2 gas sensors. Various characterization techniques, such as UV-Vis absorption, X-ray photoelectron spectroscopy, XRD, FESEM, and AFM, were used to characterize thin films for composition, structural, and morphological properties. X-ray photoelectron spectroscopy analysis revealed the presence of silver/silver oxide on SnO_2 thin films. At various hydrogen gas concentrations, the gas sensing characteristics of the produced sensors were examined. It was discovered that the manufactured sensor in greater concentrations (beginning at 600 ppm) can be detected even at room temperature [76].

In 2019, Wu et al. based High-sensitive ammonia sensors on self-assembling SnO nanoshells were made by employing a solution method and annealing at 300 °C for an hour. The as-fabricated sensors displayed responses of 313%, 874%, 2757%, 3116%, and 3757% (Δ G/G) for ammonia concentrations of (5, 20, 50, 100, and 200 parts per billion), respectively. The structure of the nanoshells, which includes curved shells that protect the core and a large surface area, allowed them to absorb more ammonia molecules, increasing the sensitivity much farther. Additionally, the SnO nanoshells showed improvement than other metal oxide ammonia sensing materials because they had larger oxygen vacancy concentrations [77].

In 2019, Beniwal et al. used Sol-gel spin coating technology to prepare SnO_2 nanostructured thin film-based gas sensor. The sensor was tested for the concentration range of 500 ppb–500 ppm for ammonia (NH₃) solution, acetone (C₃H₆O), methanol (CH₃OH), and 2-propanol (C₃H₈O) at room temperature (RT) with humidity level 1 55 % RH. With a very fast response and recovery time at RT, high response and good selectivity towards ammonia were found. The porous nanograins-based SnO₂ thin film layer, with an average particle size of 50 nm, was credited for the sensor's high response

at RT. Other characteristics of the manufactured device were high accuracy and a sizable resilience to drift behavior. The produced SnO₂ thin film's structural, chemical composition, topography, and morphological properties were examined using the results of X-Ray diffraction (XRD), X-Ray Photoelectron Spectroscopy (XPS), Atomic Force Microscopy (AFM), and Scanning Electron Microscopy (SEM), respectively. The ammonia gas sensors produced from Sample response by (313, 874, 2757, 3116, and 3757 %), respectively, for gas concentrations of 5 ppm, 20 ppm, 50 ppm, 100 ppm, and 200 ppm [78].

In 2020, Wang et al. synthesized Zinc oxide (ZnO) nanoparticles with dispersed silver (Ag) nanoparticles (Ag-ZnO) by calcining electrospun nanofiber precursors. Ag to Zn ratios of 0, 1, 3, and 5% were found in the precursor solutions. Sensor microstructure was studied using SEM and TEM. XRD and X-ray photoelectron spectroscopy revealed the presence of metallic Ag, and the characteristics of gas sensing of Ag-ZnO were studied. After mixing ZnO nanoparticles with Ag nanoparticles, the gas sensing efficiency of ethanol and hydrogen sulfide was excellent (H₂S). The response/recovery times of the 3 % of Ag-ZnO sensor to ethanol were only 5 and 9 s, respectively. However, H₂S exhibited a high response value in all of the Ag-ZnO-based gas sensors [79].

In 2020, Mehrabi et al. developed a volatile organic compound (VOCs) using a metal oxide semiconductor (MOS) sensor, which are essential for noninvasive diagnostics the control of dangerous or chemicals. Electrospinning was used to create the sensor from tin dioxide (SnO_2) and poly (ethylene oxide). Sputtering was used to achieve the gold doping of the composite nanofibers and a high-temperature oven was used for the calcination process. To establish the best fabrication parameters that produce great sensitivity, the activity of the sensor with various calcination temperatures and doping thicknesses was examined. The perfect gold dopant

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thickness was discovered to be 10 nm, However, the optimal temperature and time for calcination were determined to be 350 °C and 4 hours, respectively. [80].

In 2021, Petrov et al. developed a novel solid-phase low-temperature pyrolysis process to create thin nanocomposite films of ZnO and SnO₂ at concentrations of 0.5 to 5% mol%. To compare with electrical and gassensing properties, this hetero-oxide material was fully investigated using (XRD), (SEM), X-ray photoelectron spectroscopy (XPS), and Auger electron spectroscopy (AES) techniques. They discovered that the films are composed ZnO and SnO_2 crystals with average grain sizes in the region of 10-15 of nm. The specimen whose Sn:Zn optimum ratio was determined to be 1:99 demonstrates a 1.5-fold improvement when exposed to 5-50 parts per billion NO₂ at 200 degrees Celsius. while testing the chemical resistance of the films with various concentrations of tin dioxide. These remarkable changes have developed at this rational composite by reducing the intergrain potential barrier to 0.58 eV and raising the concentration of anionic vacancies. The results indicate that solid-phase low-temperature pyrolysis is an useful technique for modifying the oxide ratio components to modify the functional gas-sensing properties of hetero-oxide films [81].

In 2022, Tahani et al prepared ZnO thin film and a silver-doped zinc oxide nanocomposite Ag/ZnO thin film by the technique of the pulsed laser deposition at 600 °C to be applicable as a portable catalytic material for the removal of 4-nitrophenol. The nanocomposites was prepared by making the deposition of the two targets (Zn and Ag), and it was analyzed by different techniques. According to the XRD pattern, the hexagonal wurtzite crystalline form of Ag-doped ZnO NPs suggested that the samples were polycrystalline. Additionally, the shifting of the diffraction peaks to the higher angles, which denotes that doping reduces the crystallite size. From SEM images, Ag-doping drastically altered the morphological characteristics and reduced the

aggregation. Additionally, its energy band gap decreased when Ag was incorporated. UV spectroscopy was then used to monitor the catalysis process. According to the catalytic experiment results, the Ag/ZnO thin film has remarkable potential for use in environmentally-favorable applications.[82]

1.11 Aims of the Work

- 1) Study of the characteristics of (Au and Ag) nanoparticles prepared by using pulsed laser ablation in liquid (PLAL).
- Study of the characteristics of (SnO₂ and ZnO) nanostructure thin films using a sol-gel spin coating technique.
- Optimizing the conditions for preparation of Au and Ag nanoparticles embedded ZnO and SnO₂ thin films regarding their structural, electrical and optical properties.
- 4) Enhancement of gas sensor properties by embedded ZnO and SnO₂ thin films with Au and Ag NPs towards NH₃ and NO₂ gasses with high quality performance (response time, recovery time, sensitivity and stability).